

MC14051B, MC14052B, MC14053B

Analog Multiplexers/Demultiplexers

The MC14051B, MC14052B, and MC14053B analog multiplexers are digitally-controlled analog switches. The MC14051B effectively implements an SP8T solid state switch, the MC14052B a DP4T, and the MC14053B a Triple SPDT. All three devices feature low ON impedance and very low OFF leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

- Triple Diode Protection on Control Inputs
- Switch Function is Break Before Make
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range ($V_{DD} - V_{EE}$) = 3.0 to 18 V
Note: V_{EE} must be $\leq V_{SS}$
- Linearized Transfer Characteristics
- Low-noise – 12 nV/ $\sqrt{\text{Cycle}}$, $f \geq 1.0$ kHz Typical
- Pin-for-Pin Replacement for CD4051, CD4052, and CD4053
- For 4PDT Switch, See MC14551B
- For Lower R_{ON} , Use the HC4051, HC4052, or HC4053 High-Speed CMOS Devices

MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage (Referenced to V_{EE} , $V_{SS} \geq V_{EE}$)	-0.5 to +18.0	V
V_{in} , V_{out}	Input or Output Voltage Range (DC or Transient) (Referenced to V_{SS} for Control Inputs and V_{EE} for Switch I/O)	-0.5 to $V_{DD} + 0.5$	V
I_{in}	Input Current (DC or Transient) per Control Pin	± 10	mA
I_{SW}	Switch Through Current	± 25	mA
P_D	Power Dissipation, per Package (Note 2.)	500	mW
T_A	Ambient Temperature Range	-55 to +125	°C
T_{stg}	Storage Temperature Range	-65 to +150	°C
T_L	Lead Temperature (8-Second Soldering)	260	°C

1. Maximum Ratings are those values beyond which damage to the device may occur.
2. Temperature Derating:
Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

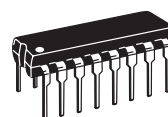
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} , V_{EE} or V_{DD}). Unused outputs must be left open.



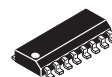
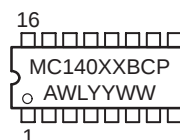
ON Semiconductor

<http://onsemi.com>

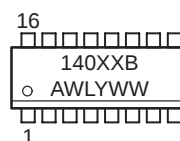
MARKING DIAGRAMS



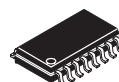
PDIP-16
P SUFFIX
CASE 648



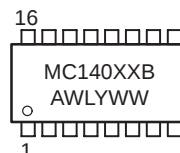
SOIC-16
D SUFFIX
CASE 751B



TSSOP-16
DT SUFFIX
CASE 948F



SOEIAJ-16
F SUFFIX
CASE 966



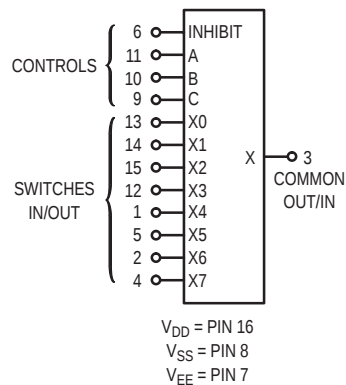
XX = Specific Device Code
A = Assembly Location
WL or L = Wafer Lot
YY or Y = Year
WW or W = Work Week

ORDERING INFORMATION

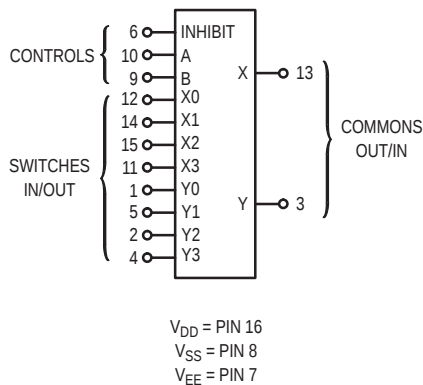
See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

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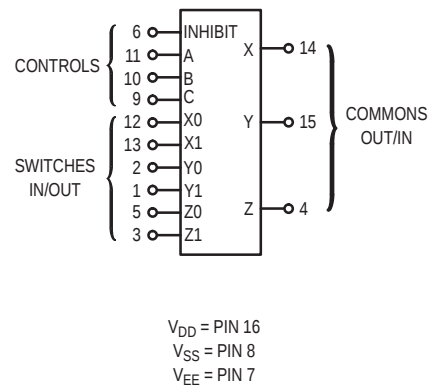
MC14051B 8-Channel Analog Multiplexer/Demultiplexer



MC14052B Dual 4-Channel Analog Multiplexer/Demultiplexer

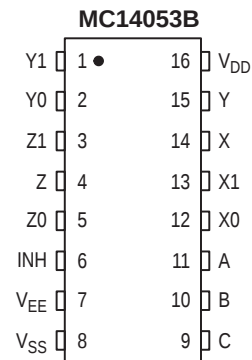
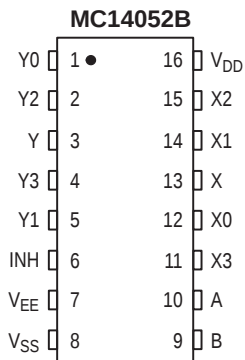
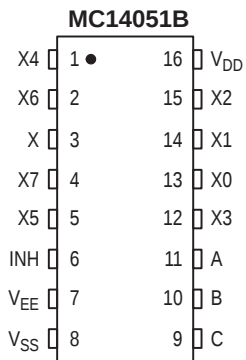


MC14053B Triple 2-Channel Analog Multiplexer/Demultiplexer



Note: Control Inputs referenced to V_{SS} , Analog Inputs and Outputs reference to V_{EE} . V_{EE} must be $\leq V_{SS}$.

PIN ASSIGNMENT



MC14051B, MC14052B, MC14053B

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	V _{DD}	Test Conditions	- 55°C		25°C			125°C		Unit
				Min	Max	Min	Typ (3.)	Max	Min	Max	

SUPPLY REQUIREMENTS (Voltages Referenced to V_{EE})

Power Supply Voltage Range	V _{DD}	—	V _{DD} - 3.0 ≥ V _{SS} ≥ V _{EE}	3.0	18	3.0	—	18	3.0	18	V
Quiescent Current Per Package	I _{DD}	5.0	Control Inputs: V _{in} = V _{SS} or V _{DD} , Switch I/O: V _{EE} ≤ V _{I/O} ≤ V _{DD} , and ΔV _{switch} ≤ 500 mV (4.)	—	5.0	—	0.005	5.0	—	150	μA
		10		—	10	—	0.010	10	—	300	
		15		—	20	—	0.015	20	—	600	
Total Supply Current (Dynamic Plus Quiescent, Per Package)	I _{D(AV)}	5.0 10 15	T _A = 25°C only (The channel component, (V _{in} - V _{out})/R _{on} , is not included.)	Typical						(0.07 μA/kHz) f + I _{DD} (0.20 μA/kHz) f + I _{DD} (0.36 μA/kHz) f + I _{DD}	μA

CONTROL INPUTS — INHIBIT, A, B, C (Voltages Referenced to V_{SS})

Low-Level Input Voltage	V _{IL}	5.0	R _{on} = per spec, I _{off} = per spec	—	1.5	—	2.25	1.5	—	1.5	V
		10		—	3.0	—	4.50	3.0	—	3.0	
		15		—	4.0	—	6.75	4.0	—	4.0	
High-Level Input Voltage	V _{IH}	5.0	R _{on} = per spec, I _{off} = per spec	3.5	—	3.5	2.75	—	3.5	—	V
		10		7.0	—	7.0	5.50	—	7.0	—	
		15		11	—	11	8.25	—	11	—	
Input Leakage Current	I _{in}	15	V _{in} = 0 or V _{DD}	—	± 0.1	—	± 0.00001	± 0.1	—	1.0	μA
Input Capacitance	C _{in}	—		—	—	—	5.0	7.5	—	—	pF

SWITCHES IN/OUT AND COMMONS OUT/IN — X, Y, Z (Voltages Referenced to V_{EE})

Recommended Peak-to-Peak Voltage Into or Out of the Switch	V _{I/O}	—	Channel On or Off	0	V _{DD}	0	—	V _{DD}	0	V _{DD}	V _{PP}
Recommended Static or Dynamic Voltage Across the Switch (4.) (Figure 5)	ΔV _{switch}	—	Channel On	0	600	0	—	600	0	300	mV
Output Offset Voltage	V _{OO}	—	V _{in} = 0 V, No Load	—	—	—	10	—	—	—	μV
ON Resistance	R _{on}	5.0	ΔV _{switch} ≤ 500 mV (4.) V _{in} = V _{IL} or V _{IH} (Control), and V _{in} = 0 to V _{DD} (Switch)	—	800	—	250	1050	—	1200	Ω
		10		—	400	—	120	500	—	520	
		15		—	220	—	80	280	—	300	
ΔON Resistance Between Any Two Channels in the Same Package	ΔR _{on}	5.0		—	70	—	25	70	—	135	Ω
		10		—	50	—	10	50	—	95	
		15		—	45	—	10	45	—	65	
Off-Channel Leakage Current (Figure 10)	I _{off}	15	V _{in} = V _{IL} or V _{IH} (Control) Channel to Channel or Any One Channel	—	± 100	—	± 0.05	± 100	—	± 1000	nA
Capacitance, Switch I/O	C _{I/O}	—	Inhibit = V _{DD}	—	—	—	10	—	—	—	pF
Capacitance, Common O/I	C _{O/I}	—	Inhibit = V _{DD} (MC14051B) (MC14052B) (MC14053B)	—	—	—	60	—	—	—	pF
				—	—	—	32	—	—	—	
				—	—	—	17	—	—	—	
Capacitance, Feedthrough (Channel Off)	C _{I/O}	—	Pins Not Adjacent Pins Adjacent	—	—	—	0.15	—	—	—	pF
		—		—	—	—	0.47	—	—	—	

3. Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.

4. For voltage drops across the switch (ΔV_{switch}) > 600 mV (> 300 mV at high temperature), excessive V_{DD} current may be drawn, i.e. the current out of the switch may contain both V_{DD} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

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ELECTRICAL CHARACTERISTICS ⁽⁵⁾ ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$) ($V_{EE} \leq V_{SS}$ unless otherwise indicated)

Characteristic	Symbol	$V_{DD} - V_{EE}$ Vdc	Typ ⁽⁶⁾ All Types	Max	Unit
Propagation Delay Times (Figure 6) Switch Input to Switch Output ($R_L = 10 \text{ k}\Omega$) MC14051 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 26.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 11 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 9.0 \text{ ns}$ MC14052 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 21.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 8.0 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 7.0 \text{ ns}$ MC14053 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 16.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 4.0 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 3.0 \text{ ns}$	t_{PLH}, t_{PHL}	5.0 10 15	35 15 12	90 40 30	ns
Inhibit to Output ($R_L = 10 \text{ k}\Omega$, $V_{EE} = V_{SS}$) Output "1" or "0" to High Impedance, or High Impedance to "1" or "0" Level MC14051B	$t_{PHZ}, t_{PLZ},$ t_{PZH}, t_{PZL}	5.0 10 15	350 170 140	700 340 280	ns
MC14052B		5.0 10 15	300 155 125	600 310 250	ns
MC14053B		5.0 10 15	275 140 110	550 280 220	ns
Control Input to Output ($R_L = 10 \text{ k}\Omega$, $V_{EE} = V_{SS}$) MC14051B	t_{PLH}, t_{PHL}	5.0 10 15	360 160 120	720 320 240	ns
MC14052B		5.0 10 15	325 130 90	650 260 180	ns
MC14053B		5.0 10 15	300 120 80	600 240 160	ns
Second Harmonic Distortion ($R_L = 10 \text{ k}\Omega$, $f = 1 \text{ kHz}$) $V_{in} = 5 V_{PP}$	—	10	0.07	—	%
Bandwidth (Figure 7) ($R_L = 1 \text{ k}\Omega$, $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p, $C_L = 50 \text{ pF}$ $20 \text{ Log } (V_{out}/V_{in}) = -3 \text{ dB}$)	BW	10	17	—	MHz
Off Channel Feedthrough Attenuation (Figure 7) $R_L = 1 \text{ k}\Omega$, $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p $f_{in} = 4.5 \text{ MHz}$ — MC14051B $f_{in} = 30 \text{ MHz}$ — MC14052B $f_{in} = 55 \text{ MHz}$ — MC14053B	—	10	- 50	—	dB
Channel Separation (Figure 8) ($R_L = 1 \text{ k}\Omega$, $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p, $f_{in} = 3.0 \text{ MHz}$)	—	10	- 50	—	dB
Crosstalk, Control Input to Common O/I (Figure 9) ($R_1 = 1 \text{ k}\Omega$, $R_L = 10 \text{ k}\Omega$ Control $t_{TLH} = t_{THL} = 20 \text{ ns}$, Inhibit = V_{SS})	—	10	75	—	mV

5. The formulas given are for the typical characteristics only at 25°C .

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

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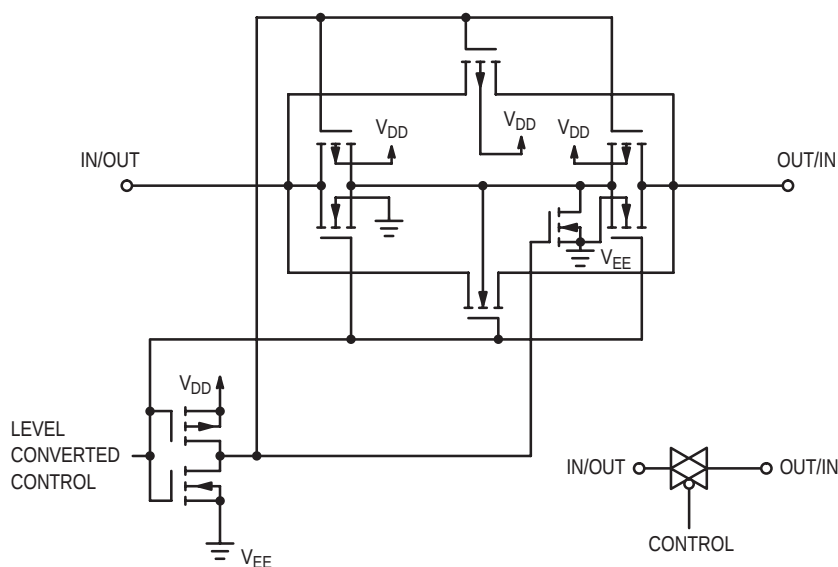


Figure 1. Switch Circuit Schematic

TRUTH TABLE

Control Inputs				ON Switches					
Inhibit	Select								
	C*	B	A	MC14051B	MC14052B	MC14053B			
0	0	0	0	X0	Y0 X0	Z0 Y0 X0			
0	0	0	1	X1	Y1 X1	Z0 Y0 X1			
0	0	1	0	X2	Y2 X2	Z0 Y1 X0			
0	0	1	1	X3	Y3 X3	Z0 Y1 X1			
0	1	0	0	X4		Z1 Y0 X0			
0	1	0	1	X5		Z1 Y0 X1			
0	1	1	0	X6		Z1 Y1 X0			
0	1	1	1	X7		Z1 Y1 X1			
1	x	x	x	None	None	None			

*Not applicable for MC14052

x = Don't Care

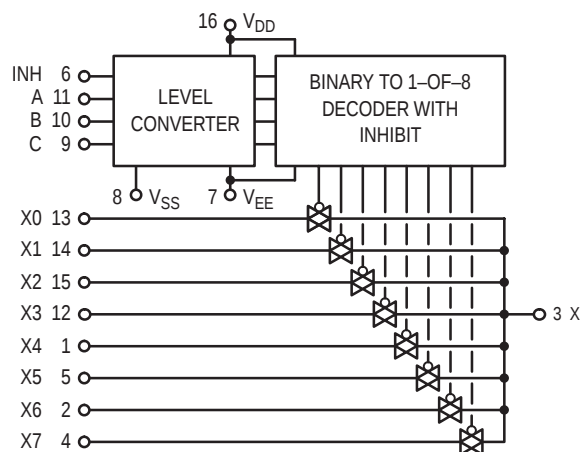


Figure 2. MC14051B Functional Diagram

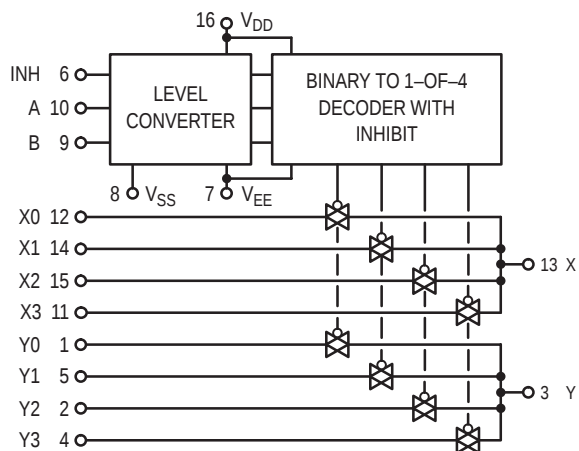


Figure 3. MC14052B Functional Diagram

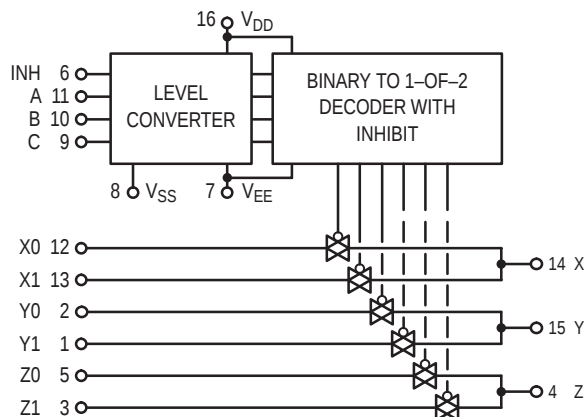


Figure 4. MC14053B Functional Diagram

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TEST CIRCUITS

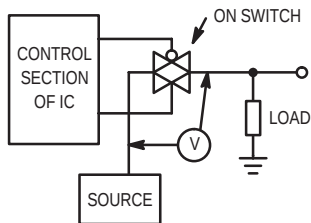


Figure 5. ΔV Across Switch

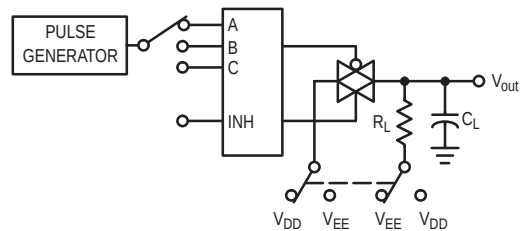


Figure 6. Propagation Delay Times, Control and Inhibit to Output

A, B, and C inputs used to turn ON or OFF the switch under test.

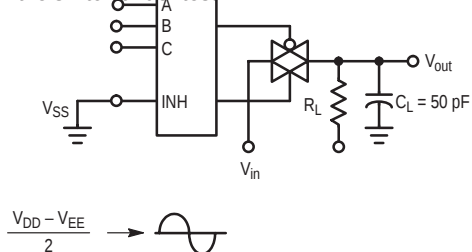


Figure 7. Bandwidth and Off-Channel Feedthrough Attenuation

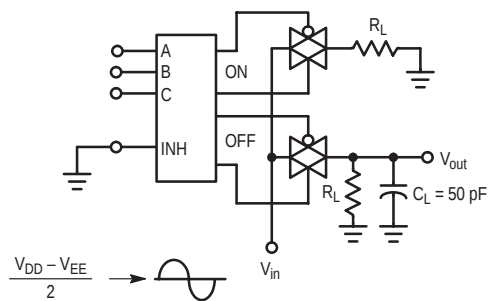


Figure 8. Channel Separation (Adjacent Channels Used For Setup)

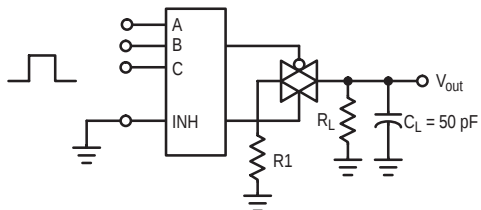


Figure 9. Crosstalk, Control Input to Common O/I

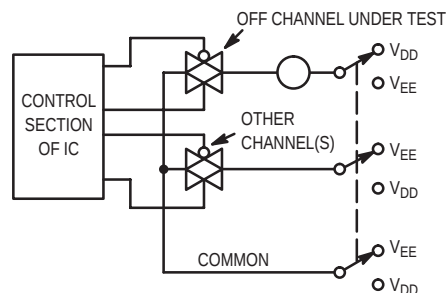


Figure 10. Off Channel Leakage

NOTE: See also Figures 7 and 8 in the MC14016B data sheet.

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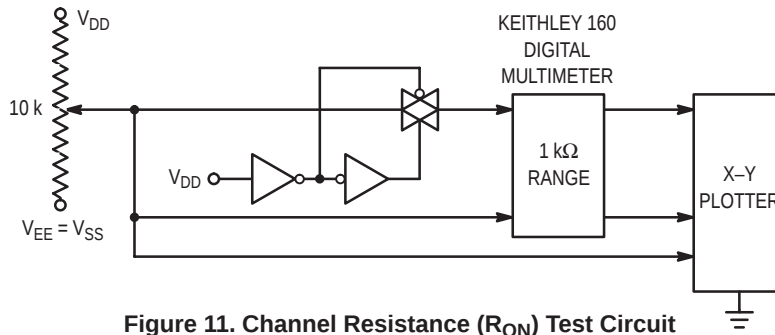


Figure 11. Channel Resistance (R_{ON}) Test Circuit

TYPICAL RESISTANCE CHARACTERISTICS

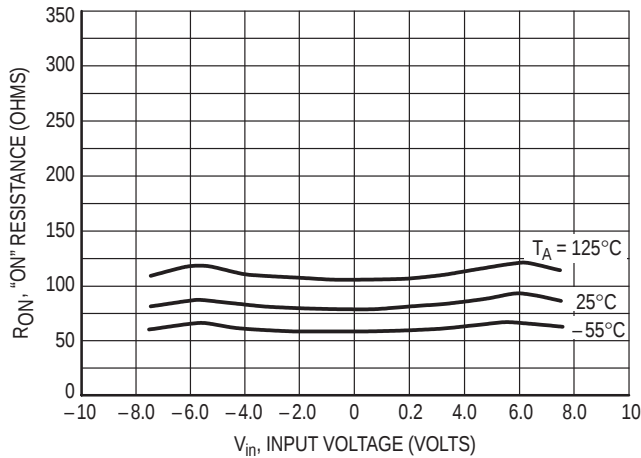


Figure 12. $V_{DD} = 7.5\text{ V}$, $V_{EE} = -7.5\text{ V}$

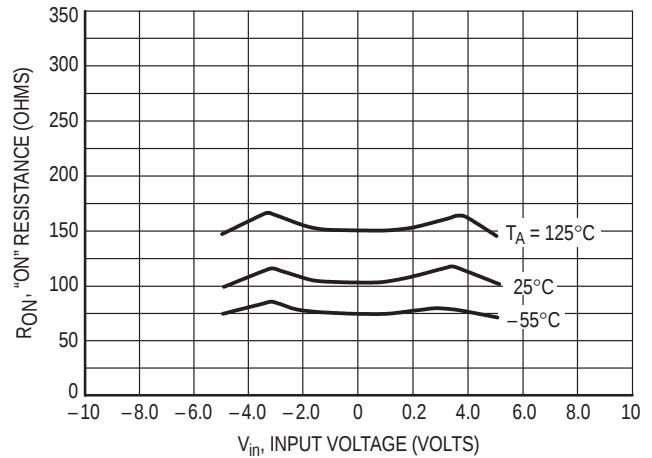


Figure 13. $V_{DD} = 5.0\text{ V}$, $V_{EE} = -5.0\text{ V}$

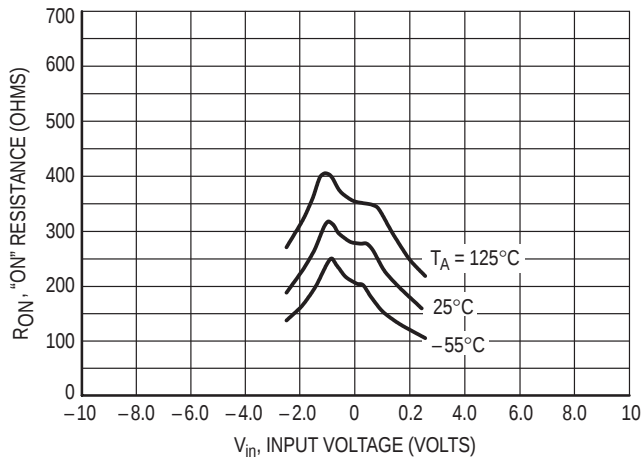


Figure 14. $V_{DD} = 2.5\text{ V}$, $V_{EE} = -2.5\text{ V}$

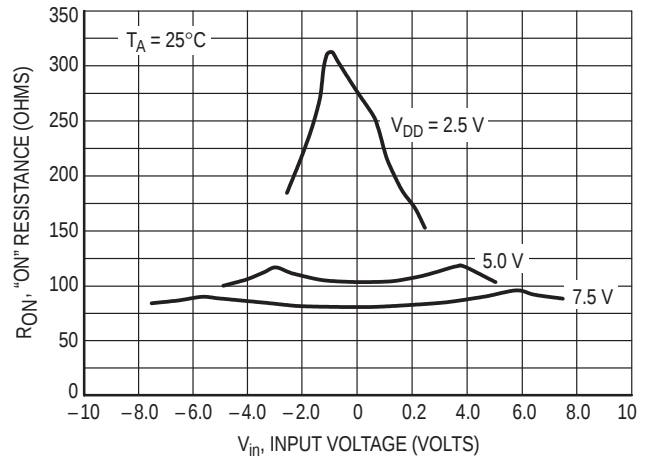


Figure 15. Comparison at 25°C , $V_{DD} = -V_{EE}$

APPLICATIONS INFORMATION

Figure A illustrates use of the on-chip level converter detailed in Figures 2, 3, and 4. The 0-to-5 V Digital Control signal is used to directly control a 9 V_{p-p} analog signal.

The digital control logic levels are determined by V_{DD} and V_{SS}. The V_{DD} voltage is the logic high voltage; the V_{SS} voltage is logic low. For the example, V_{DD} = +5 V = logic high at the control inputs; V_{SS} = GND = 0 V = logic low.

The maximum analog signal level is determined by V_{DD} and V_{EE}. The V_{DD} voltage determines the maximum recommended peak above V_{SS}. The V_{EE} voltage determines the maximum swing below V_{SS}. For the example, V_{DD} - V_{SS} = 5 V maximum swing above V_{SS}; V_{SS} - V_{EE} = 5 V maximum swing below V_{SS}. The example shows a ±4.5 V signal which allows a 1/2 volt margin at each

peak. If voltage transients above V_{DD} and/or below V_{EE} are anticipated on the analog channels, external diodes (D_x) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The *absolute* maximum potential difference between V_{DD} and V_{EE} is 18.0 V. Most parameters are specified up to 15 V which is the *recommended* maximum difference between V_{DD} and V_{EE}.

Balanced supplies are not required. However, V_{SS} must be greater than or equal to V_{EE}. For example, V_{DD} = +10 V, V_{SS} = +5 V, and V_{EE} = -3 V is acceptable. See the Table below.

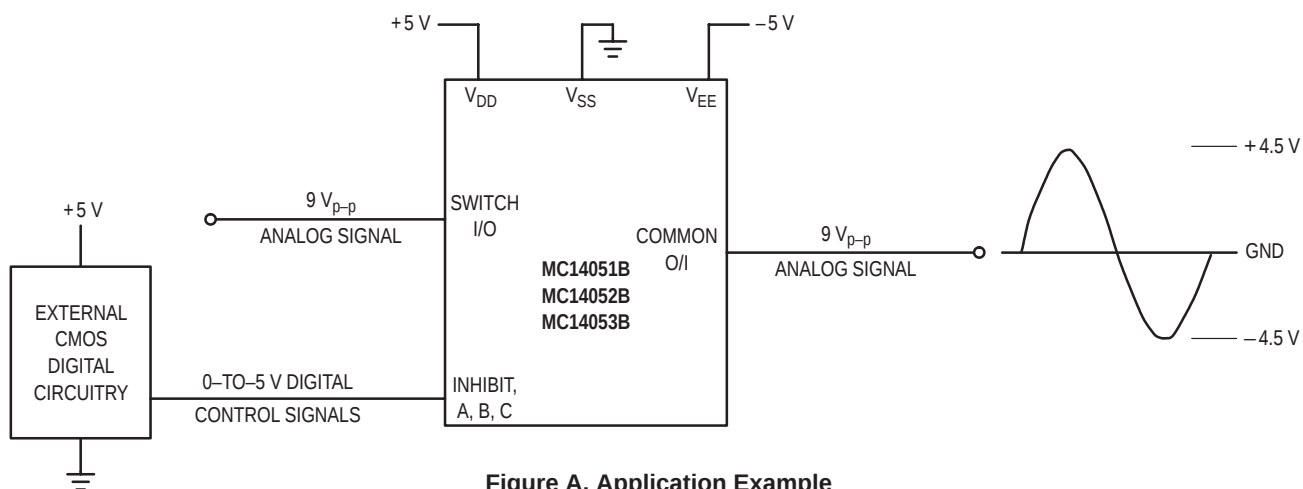


Figure A. Application Example

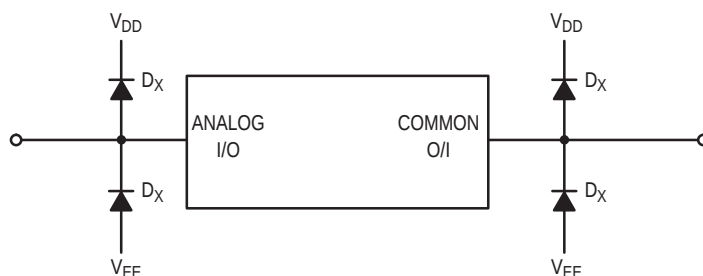


Figure B. External Germanium or Schottky Clipping Diodes

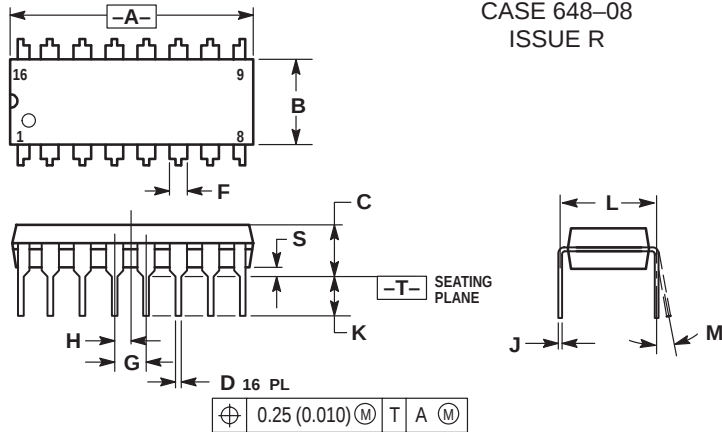
POSSIBLE SUPPLY CONNECTIONS

V _{DD} In Volts	V _{SS} In Volts	V _{EE} In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+ 8	0	- 8	+ 8/0	+ 8 to - 8 = 16 V _{p-p}
+ 5	0	- 12	+ 5/0	+ 5 to - 12 = 17 V _{p-p}
+ 5	0	0	+ 5/0	+ 5 to 0 = 5 V _{p-p}
+ 5	0	- 5	+ 5/0	+ 5 to - 5 = 10 V _{p-p}
+ 10	+ 5	- 5	+ 10/ + 5	+ 10 to - 5 = 15 V _{p-p}

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PACKAGE DIMENSIONS

PDIP-16 P SUFFIX PLASTIC DIP PACKAGE CASE 648-08 ISSUE R

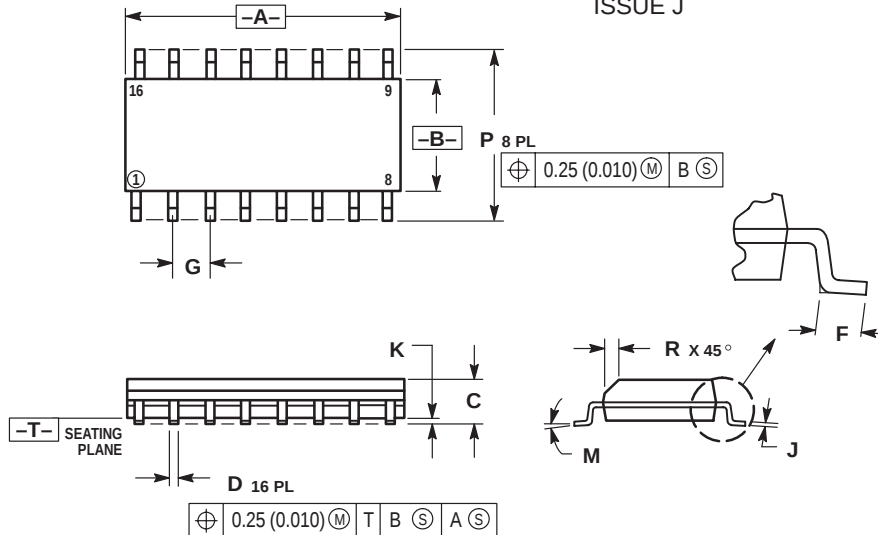


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10°	0°	10°
S	0.020	0.040	0.51	1.01

SOIC-16 D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



NOTES:

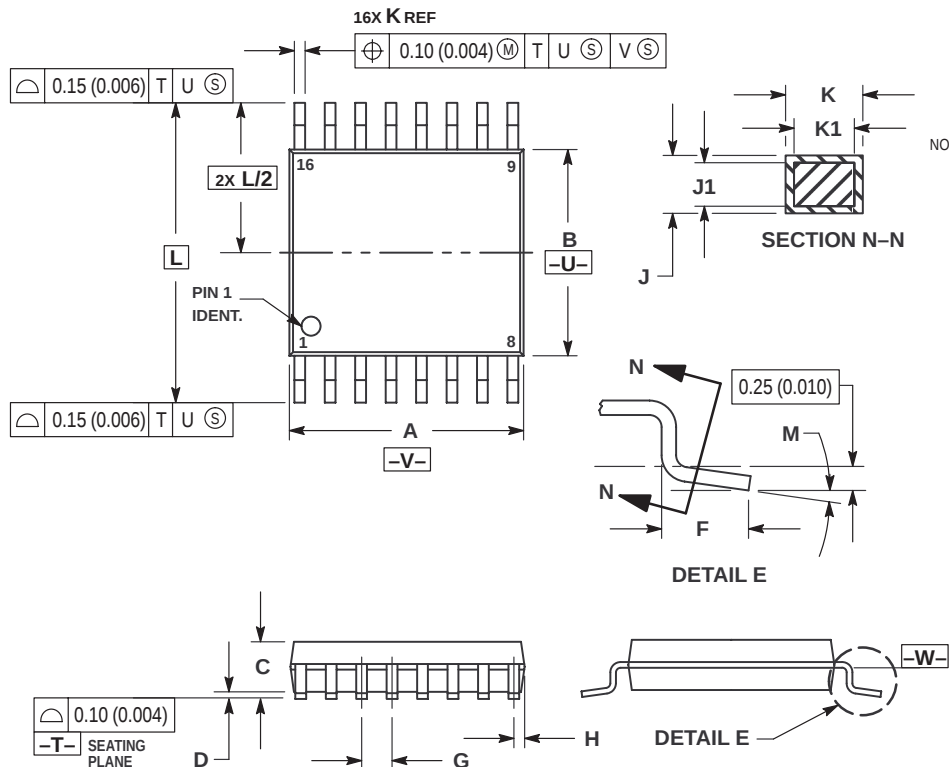
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

MC14051B, MC14052B, MC14053B

PACKAGE DIMENSIONS

TSSOP-16 DT SUFFIX PLASTIC TSSOP PACKAGE CASE 948F-01 ISSUE O



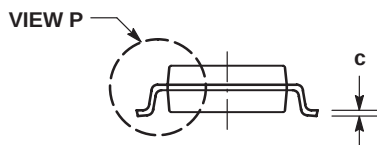
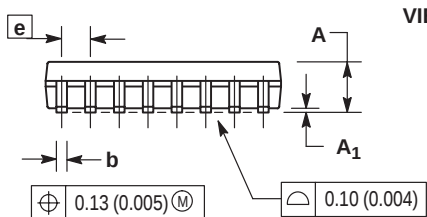
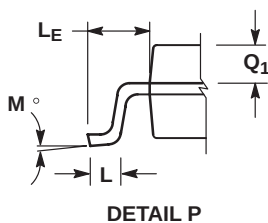
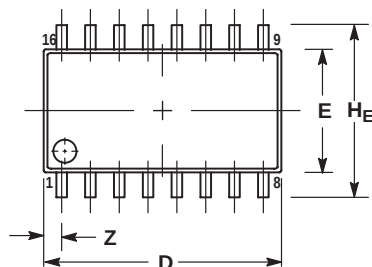
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	—	1.20	—	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

MC14051B, MC14052B, MC14053B

PACKAGE DIMENSIONS

SOEIAJ-16 F SUFFIX PLASTIC EIAJ SOIC PACKAGE CASE 966-01 ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	—	2.05	—	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H _E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L _E	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q ₁	0.70	0.90	0.028	0.035
Z	—	0.78	—	0.031

MC14051B, MC14052B, MC14053B

ORDERING & SHIPPING INFORMATION:

Device	Package	Shipping
MC14051BCP	PDIP-16	2000 Units per Box
MC14051BD	SOIC-16	48 Units per Rail
MC14051BDR2	SOIC-16	2500 Units / Tape & Reel
MC14051BDT	TSSOP-16	96 Units per Rail
MC14051BDTEL	TSSOP-16	2000 Units / Tape & Reel
MC14051BDTR2	TSSOP-16	2500 Units / Tape & Reel
MC14051BF	SOEIAJ-16	See Note 7.
MC14051BFEL	SOEIAJ-16	See Note 7.
MC14052BCP	PDIP-16	2000 Units per Box
MC14052BD	SOIC-16	48 Units per Rail
MC14052BDR2	SOIC-16	2500 Units / Tape & Reel
MC14052BDT	TSSOP-16	96 Units per Rail
MC14052BDTR2	TSSOP-16	2500 Units / Tape & Reel
MC14052BF	SOEIAJ-16	See Note 7.
MC14052BFEL	SOEIAJ-16	See Note 7.

ORDERING & SHIPPING INFORMATION:

MC14053BCP	PDIP-16	2000 Units per Box
MC14053BD	SOIC-16	48 Units per Rail
MC14053BDR2	SOIC-16	2500 Units / Tape & Reel
MC14053BDT	TSSOP-16	96 Units per Rail
MC14053BDTEL	TSSOP-16	2000 Units / Tape & Reel
MC14053BDTR2	TSSOP-16	2500 Units / Tape & Reel
MC14053BF	SOEIAJ-16	See Note 7.
MC14053BFEL	SOEIAJ-16	See Note 7.

7. For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

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